

# SHANGHAI SUNRISE ELECTRONICS CO., LTD.

## S3A THRU S3M

SURFACE MOUNT GLASS PASSIVATED RECTIFIER

TECHNICAL SPECIFICATION

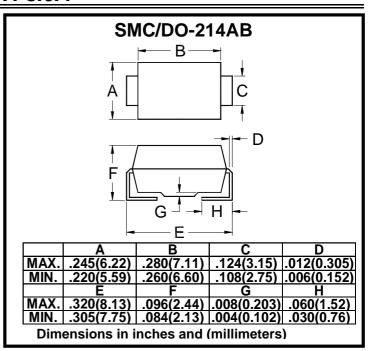
VOLTAGE: 50 TO 1000V CURRENT: 3.0A

#### **FEATURES**

- Ideal for surface mount pick and place application
- Low profile package
- Built-in strain relief
- High surge capability
- High temperature soldering guaranteed: 260°C/10sec/at terminal

#### **MECHANICAL DATA**

- Terminal: Plated leads solderable per MIL-STD 202E, method 208C
- Case: Molded with UL-94 Class V-O recognized flame retardant epoxy
- Polarity: Color band denotes cathode



### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Single-phase, half-wave, 60Hz, resistive or inductive load rating at 25°C, unless otherwise stated, for capacitive load, derate current by 20%)

| RATINGS  | SYMBOL              | S3A         | S3B | S3D | S3G | S3J | S3K | S3M  | UNITS |
|--|---------------------|-------------|-----|-----|-----|-----|-----|------|-------|
| Maximum Repetitive Peak Reverse Voltage              | $V_{RRM}$           | 50          | 100 | 200 | 400 | 600 | 800 | 1000 | V     |
| Maximum RMS Voltage                                  | $V_{RMS}$           | 35          | 70  | 140 | 280 | 420 | 560 | 700  | V     |
| Maximum DC Blocking Voltage                          | $V_{DC}$            | 50          | 100 | 200 | 400 | 600 | 800 | 1000 | V     |
| Maximum Average Forward Rectified Current            |                     | 3.0         |     |     |     |     |     |      | А     |
| (T <sub>L</sub> =75°C)                               | I <sub>F(AV)</sub>  |             |     |     |     |     |     |      |       |
| Peak Forward Surge Current (8.3ms single             | 1                   | 100         |     |     |     |     |     |      | Α     |
| half sine-wave superimposed on rated load)           | I <sub>FSM</sub>    |             |     |     |     |     |     |      | A     |
| Maximum Instantaneous Forward Voltage                | $V_{F}$             | 1.1         |     |     |     |     |     |      | V     |
| (at rated forward current)                           | ٧F                  |             |     |     |     |     |     |      |       |
| Maximum DC Reverse Current T <sub>a</sub> =25°C      | )<br> -             | 10.0        |     |     |     |     |     |      | μΑ    |
| (at rated DC blocking voltage) T <sub>a</sub> =125°C | l <sub>R</sub>      | 250         |     |     |     |     |     |      | μΑ    |
| Typical Junction Capacitance (Note 1                 | ) C <sub>J</sub>    | 40          |     |     |     |     |     |      | pF    |
| Typical Thermal Resistance (Note 2                   | R <sub>θ</sub> (ja) | 25          |     |     |     |     |     |      | °C/W  |
| Storage and Operation Junction Temperature           | $T_{STG},T_{J}$     | -65 to +150 |     |     |     |     |     |      | °C    |
| Note:  |                     |             |     |     |     |     |     |      |       |

- 1.Measured at 1.0 MHz and applied voltage of  $4.0V_{\rm dc}$
- 2. Thermal resistance from junction to terminal mounted on 5×5mm copper pad area